



YEA SHIN TECHNOLOGY CO., LTD

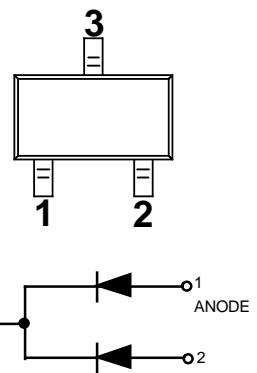
BAV70

# Monolithic Dual Switching Diode

## Common Cathode



SOT-23



Marking :A4

MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ )

Rating	Symbol	Max	Unit
Reverse Voltage	$V_R$	70	Vdc
Forward Current	$I_F$	200	mAdc
Peak Forward Surge Current	$I_{FM(surge)}$	500	mAdc

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board <sup>(1)</sup>	$P_D$	225	mW
$T_A = 25^\circ\text{C}$			
Derate above $25^\circ\text{C}$		1.8	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Device Dissipation	$P_D$	300	mW
Alumina Substrate <sup>(2)</sup> $T_A = 25^\circ\text{C}$			
Derate above $25^\circ\text{C}$		2.4	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Reverse Breakdown Voltage ( $I_{(BR)} = 100 \mu\text{Adc}$ )	$V_{(BR)}$	70	—	Vdc
Reverse Voltage Leakage Current ( $V_R = 25 \text{ Vdc}, T_J=150^\circ\text{C}$ )	$I_R$	—	60	$\mu\text{Adc}$
( $V_R = 70 \text{ Vdc}$ )		—	2.5	
( $V_R = 70 \text{ Vdc}, T_J=150^\circ\text{C}$ )		—	100	
Diode Capacitance ( $V_R = 0, f = 1.0 \text{ MHz}$ )	$C_D$	—	1.5	pF
Forward Voltage ( $I_F = 1.0 \text{ mAdc}$ )	$V_F$	—	715	mVdc
( $I_F = 10 \text{ mAdc}$ )		—	855	
( $I_F = 50 \text{ mAdc}$ )		—	1000	
( $I_F = 150 \text{ mAdc}$ )		—	1250	
Reverse Recovery Time $R_L=100\Omega$ ( $I_F=I_R=10 \text{ mAdc}, V_R=5.0 \text{ Vdc}, I_{R(REC)}=1.0 \text{ mAdc}$ ) (Figure 1)	$t_{rr}$	—	6.0	ns

1. FR-5 =  $1.0 \times 0.75 \times 0.062 \text{ in.}$ 2. Alumina =  $0.4 \times 0.3 \times 0.024 \text{ in. } 99.5\% \text{ alumina.}$

# DEVICE CHARACTERISTICS

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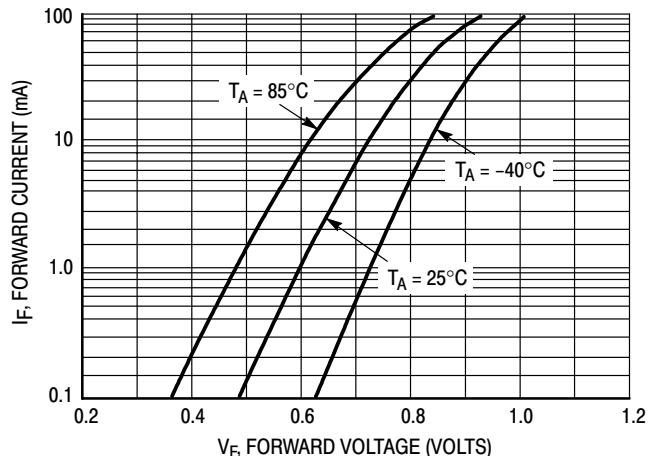


Figure 2. Forward Voltage

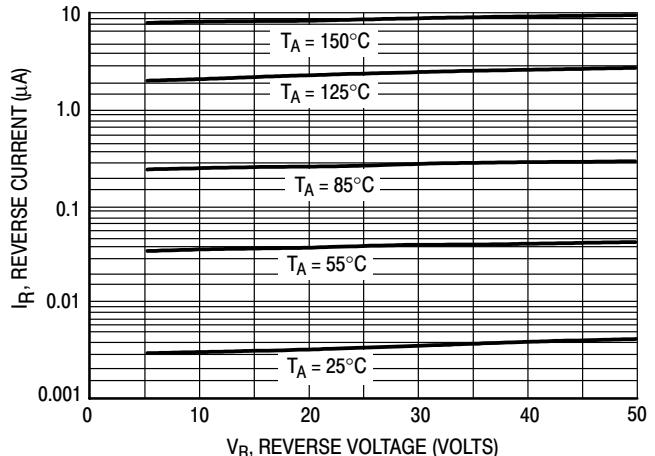


Figure 3. Leakage Current

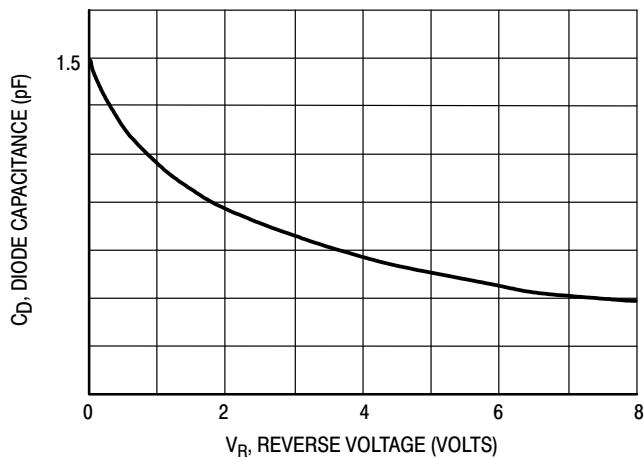
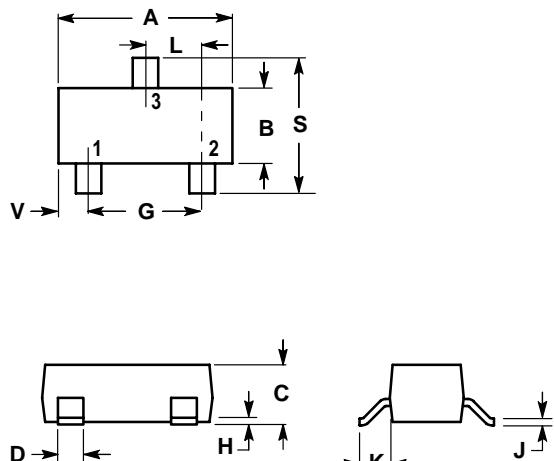


Figure 4. Capacitance

# PACKAGE OUTLINE & DIMENSIONS

## BAV70

### SOT-23



#### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

PIN 1. ANODE  
2. ANODE  
3.CATHODE

